About This Guide

This document provides introduction to the specifications of the ESP-WROOM-32 module.

The document structure is as follows:

Chapter	Title	Subject	
Chapter 1	Preface	An overview of ESP-WROOM-32	
Chapter 2	Pin Definitions	Device pinout and pin descriptions	
Chapter 3	Functional Description	Description of major functional modules and protocols	
Chapter 4	Electrical Characteristics	Electrical characteristics and specifications of ESP-WROOM-32	
Chapter 5	Schematics	The schematics of ESP-WROOM-32	
Chapter 6	Learning Resources	ESP32-related must-read materials and must-have resources	

Release Notes

Date	Version	Release notes	
2016.08	V1.0	First release.	
2016.11	V1.1	Updated Chapter 5.	
2016.11	V1.2	Added Peripheral Schematics.	
2016.12	V1.3	Updated Section 2.1.	
		Updated Chapter 1;	
		Updated Chapter 2;	
		Updated Chapter 3;	
2017.03	V1.4	Updated Table 4.2;	
		Updated Table 4.4;	
		Updated Section 4.6;	
		Added Chapter Learning Resources.	
		Updated Section 2.2;	
2017.03	V1.5	Updated Section 3.2;	
		Updated Section 3.5.1.	

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Contents

ı	Pretace	1
2 2.1 2.2	Pin Definitions Pin Layout Pin Description	3 3 4
2.3	Strapping Pins	5
3	Functional Description	7
3.1 3.2	CPU and Internal Memory External Flash and SRAM	7 7
3.3	Crystal Oscillators	7
3.4	Power Consumption	8
3.5	Peripherals and Sensors	9
	3.5.1 Peripherals and Sensors Description	9
	3.5.2 Peripheral Schematics	14
4	Electrical Characteristics	15
4.1	Absolute Maximum Ratings	15
4.2	Recommended Operating Conditions	15
4.3	Digital Terminal Characteristics	15
4.4	Wi-Fi Radio	16
4.5	Bluetooth LE Radio	16
	4.5.1 Receiver	16
	4.5.2 Transmit	17
4.6	Reflow Profile	17
5	Schematics	18
6	Learning Resources	19
6.1	Must-Read Documents	19
6.2	Must-Have Resources	19

List of Tables

1	ESP-WROOM-32 Specifications	1
2	ESP-WROOM-32 Dimensions	3
3	ESP-WROOM-32 Pin Definitions	4
4	Strapping Pins	5
5	Power Consumption by Power Modes	8
6	Peripherals and Sensors Description	9
7	Absolute Maximum Ratings	15
8	Recommended Operating Conditions	15
9	Digital Terminal Characteristics	15
10	Wi-Fi Radio Characteristics	16
11	Receiver Characteristics - BLE	16
12	Transmit Characteristics - BLE	17
13	Reflow Profile	17

List of Figures

1	Top and Side View of ESP-WROOM-32	3
2	ESP-WROOM-32 Peripheral Schematics	14
3	ESP-WROOM-32 Schematics	18

1. Preface

ESP-WROOM-32 is a powerful, generic Wi-Fi+BT+BLE MCU module that targets a wide variety of applications, ranging from low-power sensor networks to the most demanding tasks, such as voice encoding, music streaming and MP3 decoding.

At the core of this module is the ESP32-D0WDQ6 chip*, which is designed to be scalable and adaptive. There are two CPU cores that can be individually controlled or powered, and the clock frequency is adjustable from 80 MHz to 240 MHz. The user may also power off the CPU and make use of the low-power coprocessor to constantly monitor the peripherals for changes or crossing of thresholds. ESP32 integrates a rich set of peripherals, ranging from capacitive touch sensors, Hall sensors, low-noise sense amplifiers, SD card interface, Ethernet, high speed SDIO/SPI, UART, I2S and I2C.

Note:

* For details on the part number of the ESP32 series, please refer to the document ESP32 Datasheet.

The integration of Bluetooth, Bluetooth LE and Wi-Fi ensures that a wide range of applications can be targeted, and that the module is future proof: using Wi-Fi allows a large physical range and direct connection to the internet through a Wi-Fi router, while using Bluetooth allows the user to conveniently connect to the phone or broadcast low energy beacons for its detection. The sleep current of the ESP32 chip is less than 5 μ A, making it suitable for battery powered and wearable electronics applications. ESP-WROOM-32 supports data rates of up to 150 Mbps, and 22 dBm output power at the PA to ensure the widest physical range. As such the chip does offer industry-leading specifications and the best performance for electronic integration, range, power consumption, and connectivity.

The operating system chosen for ESP32 is freeRTOS with LWIP; TLS 1.2 with hardware acceleration is built in as well. Secure (encrypted) over the air (OTA) upgrade is also supported, so that developers can continually upgrade their products even after their release.

Table 1 provides the specifications of ESP-WROOM-32.

Table 1: ESP-WROOM-32 Specifications

Categories	Items	Specifications	
	Standards	FCC/CE/IC/TELEC/KCC/SRRC/NCC	
		802.11 b/g/n/d/e/i/k/r (802.11n up to 150 Mbps)	
Wi-Fi	Protocols	A-MPDU and A-MSDU aggregation and 0.4 μ s guard in-	
		terval support	
	Frequency range	2.4 ~ 2.5 GHz	
	Protocols	Bluetooth v4.2 BR/EDR and BLE specification	
		NZIF receiver with -98 dBm sensitivity	
Bluetooth	Radio	Class-1, class-2 and class-3 transmitter	
		AFH	
	Audio	CVSD and SBC	

Categories	Items	Specifications		
		SD card, UART, SPI, SDIO, I2C, LED PWM, Motor PWM,		
	Module interface	12S, I2C, IR		
	Wodule interface	GPIO, capacitive touch sensor, ADC, DAC, LNA pre-		
		amplier		
	On-chip sensor	Hall sensor, temperature sensor		
Hardware	On-board clock	40 MHz crystal		
	Operating voltage	2.2 ~ 3.6V		
	Operating current	Average: 80 mA		
	Operating temperature range	-40°C ~ 85°C *		
	Ambient temperature range	Normal temperature		
	Package size	18 mm x 25.5 mm x 2.8 mm		
	Wi-Fi mode	Station/SoftAP/SoftAP+Station/P2P		
	Security	WPA/WPA2/WPA2-Enterprise/WPS		
	Encryption	AES/RSA/ECC/SHA		
	Firmware upgrade	UART Download / OTA (via network) / download and write		
Software	i imware upgrade	firmware via host		
	Software development	Supports Cloud Server Development / SDK for custom		
	Software development	firmware development		
	Network protocols	IPv4, IPv6, SSL, TCP/UDP/HTTP/FTP/MQTT		
	User configuration	AT instruction set, cloud server, Android/iOS app		

2. Pin Definitions

2.1 Pin Layout

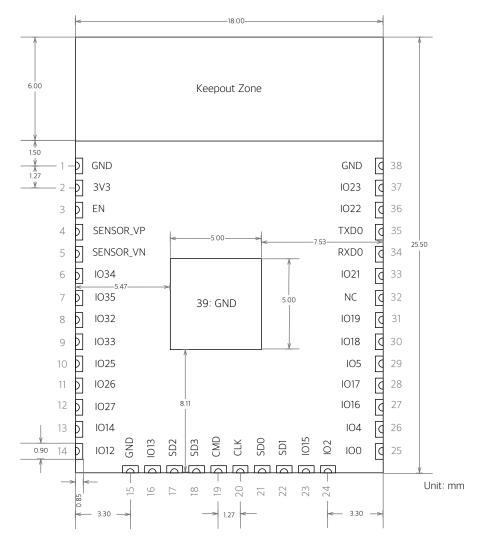


Figure 1: Top and Side View of ESP-WROOM-32

Table 2: ESP-WROOM-32 Dimensions

Length	Width	Height	PAD size (bottom)	Pin pitch	Shielding can height	PCB thickness
18 mm	25.5 mm	2.8 ± 0.1 mm	0.85 mm x 0.9 mm	1.27 mm	2 mm	$0.8 \pm 0.1 \text{ mm}$

2.2 Pin Description

ESP-WROOM-32 has 39 pins. See pin definitions in Table 3.

Table 3: ESP-WROOM-32 Pin Definitions

Name	No.	Туре	Function	
GND	1	Р	Ground	
3V3	2	Р	Power supply.	
EN	3	I	Chip-enable signal. Active high.	
SENSOR_VP	4	1	GPIO36, SENSOR_VP, ADC_H, ADC1_CH0, RTC_GPIO0	
SENSOR_VN	5	I	GPIO39, SENSOR_VN, ADC1_CH3, ADC_H, RTC_GPIO3	
IO34	6	1	GPIO34, ADC1_CH6, RTC_GPIO4	
IO35	7	I	GPIO35, ADC1_CH7, RTC_GPIO5	
1000	0	1/0	GPIO32, XTAL_32K_P (32.768 kHz crystal oscillator input), ADC1_CH4,	
IO32	8	I/O	TOUCH9, RTC_GPIO9	
1000	0	1/0	GPIO33, XTAL_32K_N (32.768 kHz crystal oscillator output), ADC1_CH5,	
IO33	9	I/O	TOUCH8, RTC_GPIO8	
IO25	10	I/O	GPIO25, DAC_1, ADC2_CH8, RTC_GPIO6, EMAC_RXD0	
IO26	11	I/O	GPIO26, DAC_2, ADC2_CH9, RTC_GPIO7, EMAC_RXD1	
1027	12	I/O	GPIO27, ADC2_CH7, TOUCH7, RTC_GPIO17, EMAC_RX_DV	
104.4	10	1/0	GPIO14, ADC2_CH6, TOUCH6, RTC_GPIO16, MTMS, HSPICLK,	
IO14	13	I/O	HS2_CLK, SD_CLK, EMAC_TXD2	
1010	4.4	1/0	GPIO12, ADC2_CH5, TOUCH5, RTC_GPIO15, MTDI, HSPIQ,	
IO12	14	I/O	HS2_DATA2, SD_DATA2, EMAC_TXD3	
GND	15	Р	Ground	
1010	10	1/0	GPIO13, ADC2_CH4, TOUCH4, RTC_GPIO14, MTCK, HSPID,	
IO13	16	I/O	HS2_DATA3, SD_DATA3, EMAC_RX_ER	
SHD/SD2*	17	I/O	GPIO9, SD_DATA2, SPIHD, HS1_DATA2, U1RXD	
SWP/SD3*	18	I/O	GPIO10, SD_DATA3, SPIWP, HS1_DATA3, U1TXD	
SCS/CMD*	19	I/O	GPIO11, SD_CMD, SPICSO, HS1_CMD, U1RTS	
SCK/CLK*	20	I/O	GPIO6, SD_CLK, SPICLK, HS1_CLK, U1CTS	
SDO/SD0*	21	I/O	GPIO7, SD_DATA0, SPIQ, HS1_DATA0, U2RTS	
SDI/SD1*	22	I/O	GPIO8, SD_DATA1, SPID, HS1_DATA1, U2CTS	
1015	00	1/0	GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICS0, RTC_GPIO13,	
IO15	23	I/O	HS2_CMD, SD_CMD, EMAC_RXD3	
100	0.4	1/0	GPIO2, ADC2_CH2, TOUCH2, RTC_GPIO12, HSPIWP, HS2_DATA0,	
IO2	24	I/O	SD_DATA0	
100	05	1/0	GPIO0, ADC2_CH1, TOUCH1, RTC_GPIO11, CLK_OUT1,	
IO0	25	I/O	EMAC_TX_CLK	
104	GPI		GPIO4, ADC2_CH0, TOUCH0, RTC_GPIO10, HSPIHD, HS2_DATA1,	
104 26 1/O SD_DATA1, EMAC_TX_ER		SD_DATA1, EMAC_TX_ER		
IO16	27	I/O	GPIO16, HS1_DATA4, U2RXD, EMAC_CLK_OUT	
IO17	28	I/O	GPIO17, HS1_DATA5, U2TXD, EMAC_CLK_OUT_180	
IO5	29	I/O	GPIO5, VSPICSO, HS1_DATA6, EMAC_RX_CLK	
IO18	30	I/O	GPIO18, VSPICLK, HS1_DATA7	
IO19	31	I/O	GPIO19, VSPIQ, U0CTS, EMAC_TXD0	

Name	No.	Туре	Function
NC	32	-	-
IO21	33	I/O	GPIO21, VSPIHD, EMAC_TX_EN
RXD0	34	I/O	GPIO3, U0RXD, CLK_OUT2
TXD0	35	I/O	GPIO1, U0TXD, CLK_OUT3, EMAC_RXD2
IO22	36	I/O	GPIO22, VSPIWP, U0RTS, EMAC_TXD1
IO23	37	I/O	GPIO23, VSPID, HS1_STROBE
GND	38	Р	Ground
GND	39	Р	Ground

Note:

2.3 Strapping Pins

ESP32-D0WDQ6 has five strapping pins. Software can read the value of these five bits from the register "GPIO_STRAPPING". During the chip power-on reset, the latches of the strapping pins sample the voltage level as strapping bits of "0" or "1", and hold these bits until the chip is powered down or shut down.

Each strapping pin is connected with its internal pull-up/pull-down during the chip reset. Consequently, if a strapping pin is unconnected or the connected external circuit is high-impedence, the internal weak pull-up/pull-down will determine the default input level of the strapping pins.

To change the strapping bit values, users can apply the external pull-down/pull-up resistances, or apply the host MCU's GPIOs to control the voltage level of these pins when powering ESP32 on.

After reset, the strapping pins work as the normal functions pins.

Refer to Table 4 for detailed boot modes of configuration by strapping pins.

Table 4: Strapping Pins

	Voltage of Internal LDO (VDD_SDIO)						
Pin	Default	3.0	3V	1.8V			
MTDI	Pull-down	()	-	1		
			Booting Mode				
Pin	Default	SPI Flas	sh Boot	Downlo	ad Boot		
GPI00	Pull-up	-	1	()		
GPIO2	Pull-down	Don't	-care	0			
		Debugging	g Log on U0TXD During	Booting			
Pin	Default	U0TXD T	Toggling	U0TXD Silent			
MTDO	Pull-up	-	1	()		
			Timing of SDIO Slave				
Pin	Default	Falling-edge Input	Falling-edge Input	Rising-edge Input	Rising-edge Input		
FIII	Delault	Falling-edge Output	Rising-edge Output	Falling-edge Output	Rising-edge Output		
MTDO	Pull-up	0	0	1	1		
GPIO5	Pull-up	0 1		0	1		

^{*} Pins SCK/CLK, SDO/SD0, SDI/SD1, SHD/SD2, SWP/SD3 and SCS/CMD, namely, GPIO6 to GPIO11 are connected to the integrated SPI flash integrated on ESP-WROOM-32 and are not recommended for other uses.

Note:

Firmware can configure register bits to change the settings of "Voltage of Internal LDO (VDD_SDIO)" and "Timing of SDIO Slave" after booting.

3. Functional Description

This chapter describes the modules and functions integrated in ESP-WROOM-32.

3.1 CPU and Internal Memory

ESP32-DOWDQ6 contains two low-power Xtensa® 32-bit LX6 microprocessors. The internal memory includes:

- 448 KB of ROM for booting and core functions.
- 520 KB of on-chip SRAM for data and instruction.
- 8 KB of SRAM in RTC, which is called RTC SLOW Memory and can be accessed by the co-processor during the Deep-sleep mode.
- 8 KB of SRAM in RTC, which is called RTC FAST Memory and can be used for data storage; it is accessed
 by the main CPU during RTC Boot from the Deep-sleep mode.
- 1 kbit of eFuse, of which 256 bits are used for the system (MAC address and chip configuration) and the remaining 768 bits are reserved for customer applications, including Flash-Encryption and Chip-ID.

3.2 External Flash and SRAM

ESP32-DOWDQ6 supports up to four 16-MB external QSPI flash and SRAM with hardware encryption based on AES to protect developer's programs and data.

ESP32 can access the external QSPI flash and SRAM through high-speed caches.

- Up to 16 MB of external flash are memory-mapped onto the CPU code space, supporting 8, 16 and 32-bit access. Code execution is supported.
- Up to 8 MB of external flash/SRAM are memory-mapped onto the CPU data space, supporting 8, 16 and 32-bit access. Data-read is supported on the flash and SRAM. Data-write is supported on the SRAM.

ESP-WROOM-32 integrates 4 MB of external SPI flash. The 4-MB SPI flash can be memory-mapped onto the CPU code space, supporting 8, 16 and 32-bit access. Code execution is supported. The integrated SPI flash is connected to GPIO6, GPIO7, GPIO8, GPIO9, GPIO10 and GPIO11. These six pins cannot be used as regular GPIO.

3.3 Crystal Oscillators

The frequencies of the main crystal oscillator supported include 40 MHz, 26 MHz and 24 MHz. The accuracy of crystal oscillators applied should be ± 10 PPM, and the operating temperature ranges from -40°C to 85°C.

When using the downloading tools, remember to select the right crystal oscillator type. In circuit design, capacitors C1 and C2 that connect to the earth are added to the input and output terminals of the crystal oscillator, respectively. The values of the two capacitors can be flexible, ranging from 6 pF to 22 pF. However, the specific capacitive values of C1 and C2 depend on further tests and adjustments of the overall performance of the whole circuit. Normally, the capacitive values of C1 and C2 are within 10 pF when the crystal oscillator frequency is 26 MHz, or 10 pF<C1 and C2<22 pF when the crystal oscillator frequency is 40 MHz.

The frequency of the RTC crystal oscillator is typically 32 kHz or 32.768 kHz. The accuracy can be out of the range of ± 20 PPM, when the internal calibration is applied to correct the frequency offset. When the chip operates in low-power modes, the application chooses the external low-speed (32 kHz) crystal clock, rather than the internal RC oscillators, to achieve the accurate wakeup time.

3.4 Power Consumption

With the advanced power management technology, ESP32-D0WDQ6 can switch between different power modes as follows:

Power mode

- Active mode: chip radio is powered on. The chip can receive, transmit, or listen.
- Modem-sleep mode: the CPU is operational and the clock is configurable. Wi-Fi / Bluetooth baseband and radio are disabled.
- Light-sleep mode: the CPU is paused. The RTC and ULP-coprocessor are running. Any wake-up events (MAC, host, RTC timer, or external interrupts) will wake up the chip.
- Deep-sleep mode: Only RTC is powered on. Wi-Fi and Bluetooth connection data are stored in RTC memory. The ULP-coprocessor can work.
- Hibernation mode: The internal 8MHz oscillator and ULP-coprocessor are disabled. The RTC recovery
 memory is powered down. Only one RTC timer on the slow clock and some RTC GPIOs are active.
 The RTC timer or the RTC GPIOs can wake up the chip from the Hibernation mode.

• Sleep Pattern

- Association sleep pattern: The power mode switches between the active mode and Modem-sleep/Light-sleep mode during this sleep pattern. The CPU, Wi-Fi, Bluetooth, and radio wake up at pre-determined intervals to keep Wi-Fi / BT connections on.
- ULP sensor-monitored pattern: The main CPU is in the Deep-sleep mode. The ULP co-processor does sensor measurements and wakes up the main system, based on the measured data from sensors.

The power consumption varies with different power modes/sleep patterns, and work status, of functional modules (see Table 5).

Power mode	Comment	Power consumption
	Wi-Fi Tx packet 13 dBm ~ 21 dBm	160 ~ 260 mA
	Wi-Fi / BT Tx packet 0 dBm	120 mA
Active mode (RF working)	Wi-Fi / BT Rx and listening	80 ~ 90 mA
	Association sleep pattern (by Light-	0.9 mA@DTIM3, 1.2 mA@DTIM1
	sleep)	
		Max speed: 20 mA
Modem-sleep mode	The CPU is powered on.	Normal: 5 ~ 10 mA
		Slow speed: 3 mA
Light-sleep mode	-	0.8 mA

Table 5: Power Consumption by Power Modes

Power mode	Comment	Power consumption
	The ULP-coprocessor is powered on.	0.15 mA
Deep-sleep mode	ULP sensor-monitored pattern	25 μA @1% duty
	RTC timer + RTC memories	20 μΑ
Hibernation mode	RTC timer only	5 μΑ

3.5 Peripherals and Sensors

3.5.1 Peripherals and Sensors Description

Table 6: Peripherals and Sensors Description

Interface	Signal	Pin	Function
	ADC1_CH0	SENSOR_VP	
	ADC1_CH3	SENSOR_VN	
	ADC1_CH4	IO32	
	ADC1_CH5	IO33	
	ADC1_CH6	IO34	
	ADC1_CH7	IO35	
	ADC2_CH0	104	
ADC	ADC2_CH1	100	Two 12-bit SAR ADCs
	ADC2_CH2	102	
	ADC2_CH3	IO15	
	ADC2_CH4	IO13	
	ADC2_CH5	IO12	
	ADC2_CH6	IO14	
	ADC2_CH7	1027	
	ADC2_CH8	IO25	
	ADC2_CH9	IO26	
Ultra Low Noise	SENSOR_VP	IO36	Provides about 60dB gain by using larger
Analog Pre-Amplifier	SENSOR_VN	IO39	capacitors on PCB
DAC	DAC_1	IO25	Two 8-bit DACs
DAC	DAC_2	IO26	TWO 0-DIL DAGS
	TOUCH0	104	
	TOUCH1	IO0	
	TOUCH2	102	
	TOUCH3	IO15	
Touch Sensor	TOUCH4	IO13	Capacitive touch sensors
	TOUCH5	IO12	
	TOUCH6	IO14	
	TOUCH7	1027	
	TOUCH8	IO33	
	TOUCH9	IO32	

Interface	Signal	Pin	Function		
	HS2_CLK	MTMS			
	HS2_CMD	MTDO			
SD / SDIO / MMC	HS2_DATA0	IO2	Supports SD memory card V3.01 standard		
Host Controller	HS2_DATA1	IO4	Supports 3D memory card vo.or standard		
	HS2_DATA2	MTDI			
	HS2_DATA3	MTCK			
	PWM0_OUT0~2				
	PWM1_OUT_IN0~2		Three channels of 16-bit timers generate		
	PWM0_FLT_IN0~2		PWM waveforms; each has a pair of		
Motor PWM	PWM1_FLT_IN0~2	Any GPIOs*	output signals. Three fault detection		
TVIOLOT T VVIVI	PWM0_CAP_IN0~2	Triy Gir 100	signals. Three event capture signals. Three		
	PWM1_CAP_IN0~2		sync signals.		
	PWM0_SYNC_IN0~2				
	PWM1_SYNC_IN0~2				
LED PWM	ledc_hs_sig_out0~7	- Any GPIOs*	16 independent channels @80MHz		
	ledc_ls_sig_out0~7	Ally GFIOS	clock/RTC CLK. Duty accuracy: 16 bits.		
	U0RXD_in				
	U0CTS_in				
	U0DSR_in				
	U0TXD_out				
	U0RTS_out				
	U0DTR_out				
UART	U1RXD_in	Any GPIOs*	Two UART devices with hardware		
	U1CTS_in		flow-control and DMA		
	U1TXD_out				
	U1RTS_out				
	U2RXD_in				
	U2CTS_in				
	U2TXD_out				
	U2RTS_out				
	I2CEXT0_SCL_in				
	I2CEXTO_SDA_in				
	I2CEXT1_SCL_in				
I2C	I2CEXT1_SDA_in	Any GPIOs*	Two I2C devices in slave or master modes		
	I2CEXT0_SCL_out	7 trly Cir 100	Two 120 devises in diave of madel modes		
	I2CEXT0_SDA_out				
	I2CEXT1_SCL_out				
	I2CEXT1_SDA_out				

Interface	Signal	Pin	Function		
	I2S0I_DATA_in0~15				
	I2S0O_BCK_in				
	12S0O_WS_in				
	I2S0I_BCK_in				
	12S0I_WS_in				
	I2S0I_H_SYNC				
	I2S0I_V_SYNC				
	I2S0I_H_ENABLE				
	I2S0O_BCK_out				
	I2S0O_WS_out				
128	I2S0I_BCK_out	Any GPIOs*			
	I2S0I_WS_out		Ctores input and output from to the guidin		
	I2S0O_DATA_out0~23		Stereo input and output from/to the audio codec, and parallel LCD data output		
	I2S1I_DATA_in0~15		codec, and parallel LCD data output		
	I2S1O_BCK_in				
	12S10_WS_in				
	I2S1I_BCK_in				
	I2S1I_WS_in				
	I2S1I_H_SYNC				
	I2S1I_V_SYNC				
	I2S1I_H_ENABLE				
	I2S1O_BCK_out				
	I2S1O_WS_out				
	I2S1I_BCK_out				
	I2S1I_WS_out				
	I2S1O_DATA_out0~23				
Remote Controller	RMT_SIG_IN0~7	Any GPIOs*	Eight channels of IR transmitter and		
Lemote Controllet	RMT_SIG_OUT0~7	Ally GFIOS	receiver for various waveforms		

Interface	Signal	Pin	Function
	SPIHD	SHD/SD2	
	SPIWP	SWP/SD3	
	SPICS0	SCS/CMD	
	SPICLK	SCK/CLK	
	SPIQ	SDO/SD0	
	SPID	SDI/SD1	
	HSPICLK	IO14	
	HSPICS0	IO15	Supports Standard SPI, Dual SPI, and
Parallel QSPI	HSPIQ	IO12	Quad SPI that can be connected to the
	HSPID	IO13	external flash and SRAM
	HSPIHD	104	
	HSPIWP	IO2	
	VSPICLK	IO18	
	VSPICS0	IO5	
	VSPIQ	IO19	
	VSPID	IO23	
	VSPIHD	IO21	
	VSPIWP	IO22	
	HSPIQ_in/_out		Standard SPI consists of clock,
	HSPID_in/_out		chip-select, MOSI and MISO. These SPIs
	HSPICLK_in/_out		can be connected to LCD and other
	HSPI_CS0_in/_out		external devices. They support the
	HSPI_CS1_out		following features:
General Purpose	HSPI_CS2_out	Any GPIOs*	 both master and slave modes;
SPI	VSPIQ_in/_out		4 sub-modes of the SPI format
	VSPID_in/_out		transfer that depend on the clock
	VSPICLK_in/_out		phase (CPHA) and clock polarity
	VSPI_CS0_in/_out		(CPOL) control;
	VSPI_CS1_out		CLK frequencies by a divider; What is a fall of the condition of
	VSPI_CS2_out		 up to 64 bytes of FIFO and DMA.
	MTDI	IO12	
JTAG	MTCK	IO13	JTAG for software debugging
UIAG	MTMS	IO14	o in a fortware debugging
	MTDO	IO15	

Interface	Signal	Pin	Function
	SD_CLK	IO6	SDIO interface that conforms to the
	SD_CMD	IO11	industry standard SDIO 2.0 card
SDIO Slave	SD_DATA0	IO7	specification. On ESP-WROOM-32 these
	SD_DATA1	IO8	pins are connected to the integrated SPI
	SD_DATA2	IO9	flash.
	SD_DATA3	IO10	
	EMAC_TX_CLK	IO0	
	EMAC_RX_CLK	IO5	
	EMAC_TX_EN	IO21	
	EMAC_TXD0	IO19	
	EMAC_TXD1	IO22	
	EMAC_TXD2	IO14	
	EMAC_TXD3	IO12	
	EMAC_RX_ER	IO13	
	EMAC_RX_DV	IO27	
EN 44 O	EMAC_RXD0	IO25	511
EMAC	EMAC_RXD1	IO26	Ethernet MAC with MII/RMII interface
	EMAC_RXD2	TXD	
	EMAC_RXD3	IO15	
	EMAC_CLK_OUT	IO16	
	EMAC_CLK_OUT_180	IO17	
	EMAC_TX_ER	IO4	
	EMAC_MDC_out	Any GPIOs*	
	EMAC_MDI_in	Any GPIOs*	
	EMAC_MDO_out	Any GPIOs*	
	EMAC_CRS_out	Any GPIOs*	
	EMAC_COL_out	Any GPIOs*	

Note:

- Functions of Motor PWM, LED PWM, UART, I2C, I2S, general purpose SPI and Remote Controller can be configured to any GPIO except GPIO6, GPIO7, GPIO8, GPIO9, GPIO10 and GPIO11.
- In Table 6, for the items marked with "Any GPIOs*" in the "Pin" column, users should note that GPIO6, GPIO7, GPIO8, GPIO9, GPIO10 and GPIO11 are connected to the integrated SPI flash of ESP-WROOM-32 and are not recommended for other uses.

3.5.2 Peripheral Schematics

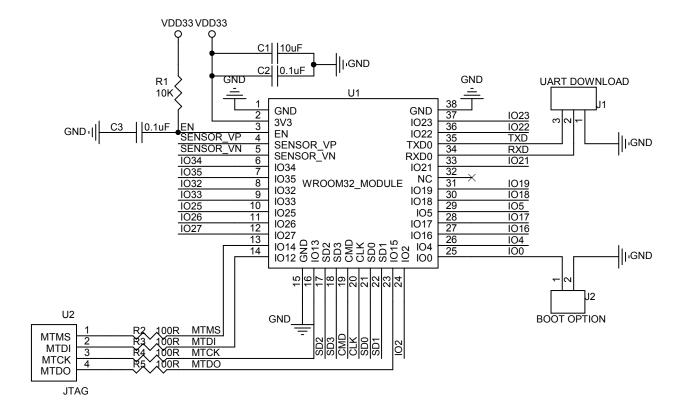


Figure 2: ESP-WROOM-32 Peripheral Schematics

Note:

The MTDI should be kept at low electric level.

4. Electrical Characteristics

Note:

The specifications in this chapter have been tested under the following general condition: $V_{BAT} = 3.3V$, $T_A = 27$ °C, unless otherwise specified.

4.1 Absolute Maximum Ratings

Table 7: Absolute Maximum Ratings

Rating	Condition	Value	Unit
Storage temperatue	-	-40 ~ 85	°C
Maximum soldering temperature	-	260	°C
Supply voltage	IPC/JEDEC J-STD-020	+2.2 ~ +3.6	V

4.2 Recommended Operating Conditions

Table 8: Recommended Operating Conditions

Operating condition	Symbol	Min	Тур	Max	Unit
Operating temperature	-	-40	20	85	°C
Supply voltage	VDD	2.2	3.3	3.6	V
Operating current	I_{VDD}	0.5	-	-	А

4.3 Digital Terminal Characteristics

Table 9: Digital Terminal Characteristics

Terminals	Symbol	Min	Тур	Max	Unit
Input logic level low	V_{IL}	-0.3	-	0.25VDD	V
Input logic level high	V_{IH}	0.75VDD	-	VDD+0.3	V
Output logic level low	V_{OL}	N	-	0.1VDD	V
Output logic level high	V_{OH}	0.8VDD	-	N	V

4.4 Wi-Fi Radio

Table 10: Wi-Fi Radio Characteristics

Description	Min	Тур	Max	Unit
	General Charact	eristics		
Input frequency	2412	-	2484	MHz
Input impedance	-	50	-	Ω
Input reflection	-	-	-10	dB
Output power of PA	15.5	19.5	21.5	dBm
	Sensitivity	′		
DSSS, 1 Mbps	-	-98	-	dBm
CCK, 11 Mbps	-	-90	-	dBm
OFDM, 6 Mbps	-	-93	-	dBm
OFDM, 54 Mbps	-	-75	-	dBm
HT20, MCS0	-	-93	-	dBm
HT20, MCS7	-	-73	-	dBm
HT40, MCS0	-	-90	-	dBm
HT40, MCS7	-	-70	-	dBm
MCS32	-	-91	-	dBm
A	djacent Channel	Rejection		
OFDM, 6 Mbps	-	37	-	dB
OFDM, 54 Mbps	-	21	-	dB
HT20, MCS0	-	37	-	dB
HT20, MCS7	-	20	-	dB

4.5 Bluetooth LE Radio

4.5.1 Receiver

Table 11: Receiver Characteristics - BLE

Parameter	Conditions	Min	Тур	Max	Unit
Sensitivity @0.1% BER	-	-	-98	-	dBm
Maximum received signal @0.1% BER	-	0	-	-	dBm
Co-channel C/I	-	-	+10	-	dB
Adjacent channel selectivity C/I	F = F0 + 1 MHz	-	-5	-	dB
	F = F0 - 1 MHz	-	-5	-	dB
	F = F0 + 2 MHz	-	-25	-	dB
	F = F0 - 2 MHz	-	-35	-	dB
	F = F0 + 3 MHz	-	-25	-	dB
	F = F0 - 3 MHz	-	-45	-	dB
	30 MHz - 2000 MHz	-10	-	-	dBm
Out of hand blocking performance	2000 MHz - 2400 MHz	-27	-	-	dBm
Out-of-band blocking performance	2500 MHz - 3000 MHz	-27	-	-	dBm
	3000 MHz - 12.5 GHz	-10	-	-	dBm
Intermodulation	-	-36	-	-	dBm

4.5.2 Transmit

Table 12: Transmit Characteristics - BLE

Parameter	Conditions	Min	Тур	Max	Unit
RF transmit power	-	-	+7.5	+10	dBm
RF power control range	-	-	25	-	dB
	F = F0 + 1 MHz	-	-14.6	-	dBm
Adjacent channel transmit power	F = F0 - 1 MHz	-	-12.7	-	dBm
	F = F0 + 2 MHz	-	-44.3	-	dBm
	F = F0 - 2 MHz	-	-38.7	-	dBm
	F = F0 + 3 MHz	-	-49.2	-	dBm
	F = F0 - 3 MHz	-	-44.7	-	dBm
	F = F0 + > 3 MHz	-	-50	-	dBm
	F = F0 - > 3 MHz	-	-50	-	dBm
Δ f1 $_{avg}$	-	-	-	265	kHz
Δ f2 $_{max}$	-	247	-	-	kHz
Δ f2 $_{avg}$ / Δ f1 $_{avg}$	-	-	-0.92	-	-
ICFT	-	-	-10	-	kHz
Drift rate	-	-	0.7	-	kHz/50 μs
Drift	-	-	2	-	kHz

4.6 Reflow Profile

Table 13: Reflow Profile

Item	Value
T_s max to TL (Ramp-up Rate)	3°C/second max
Preheat	
Temperature Min. (T _s Min.)	150°C
Temperature Typ. (T_s Typ.)	175°C
Temperature Min. (T _s Max.)	200°C
Time (T_s)	60 ~ 180 seconds
Ramp-up rate (T_L to T_P)	3°C/second max
Time maintained above: $-$ Temperature (T_L) /Time (T_L)	217°C/60 ~ 150 seconds
Peak temperature (T_P)	260°C max, for 10 seconds
Target peak temperature (T _P Target)	260°C +0/-5°C
Time within 5°C of actual peak (t_P)	20 ~ 40 seconds
T_S max to T_L (Ramp-down Rate)	6°C/second max
Tune 25°C to Peak Temperature (t)	8 minutes max